# 74AHC1GU04-Q100

Inverter

Rev. 1 — 21 November 2012

#### 1. General description

The 74AHC1GU04-Q100 is a high-speed Si-gate CMOS device. It provides an inverting single stage function.

The AHC device has CMOS input switching levels and supply voltage range 2 V to 5.5 V.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

#### 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
   Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Symmetrical output impedance
- High noise immunity
- Low power dissipation
- Balanced propagation delays
- ESD protection:
  - ◆ MIL-STD-883, method 3015 exceeds 2000 V
  - HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)

## 3. Ordering information

#### Table 1.Ordering information

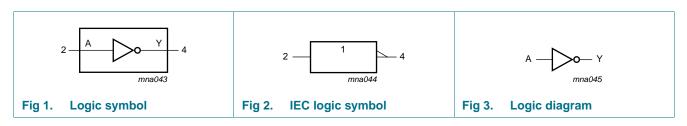
Type number	Package							
	Temperature range	Name	Description	Version				
74AHC1GU04GW-Q100	–40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1				
74AHC1GU04GV-Q100	–40 °C to +125 °C	SC-74A	plastic surface-mounted package; 5 leads	SOT753				

#### 4. Marking

Table 2. Marking codes	
Type number	Marking
74AHC1GU04GW-Q100	AD
74AHC1GU04GV-Q100	AU4

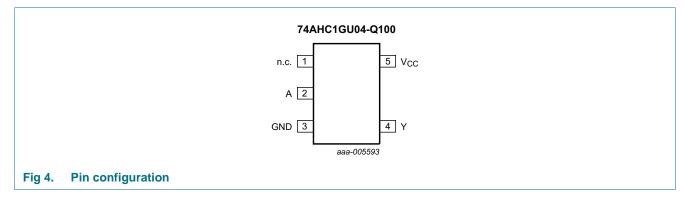


# 5. Functional diagram



# 6. Pinning information

# 6.1 Pinning



## 6.2 Pin description

Symbol	Pin	Description	
n.c.	1	not connected	
A	2	data input	
GND	3	ground (0 V)	
Y	4	data output	
V <sub>CC</sub>	5	supply voltage	

# 7. Functional description

#### Table 4.Function table

*H* = *HIGH* voltage level; *L* = *LOW* voltage level

Input	Output
A	Y
L	Н
Н	L

# 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+7.0	V
I <sub>IK</sub>	input clamping current	$V_{I} < -0.5 V$	-20	-	mA
VI	input voltage		<u>[1]</u> –0.5	+7.0	V
I <sub>OK</sub>	output clamping current	$V_{\rm O}$ < –0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V	-	±20	mA
lo	output current	$-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$	-	±25	mA
I <sub>CC</sub>	supply current		-	75	mA
I <sub>GND</sub>	ground current		-75	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40 \ ^{\circ}C \ to +125 \ ^{\circ}C$	[2] _	250	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For both TSSOP5 and SC-74A packages: above 87.5  $^\circ$ C the value of P<sub>tot</sub> derates linearly with 4.0 mW/K.

# 9. Recommended operating conditions

#### Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

•		,				
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>CC</sub>	supply voltage		2.0	5.0	5.5	V
VI	input voltage		0	-	5.5	V
Vo	output voltage		0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	$V_{CC}$ = 3.3 V $\pm$ 0.3 V	-	-	100	ns/V
		$V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$	-	-	20	ns/V

# **10. Static characteristics**

#### Table 7.Static characteristics

Voltages are referenced to GND (ground = 0 V).

Symbol	Symbol Parameter Conditions		25 °C			–40 °C to +85 °C		–40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
VIH	HIGH-level	V <sub>CC</sub> = 2.0 V	1.7	-	-	1.7	-	1.7	-	V
	input voltage	$V_{CC} = 3.0 V$	2.4	-	-	2.4	-	2.4	-	V
		$V_{CC} = 5.5 V$	4.4	-	-	4.4	-	4.4	-	V
VIL	LOW-level	$V_{CC} = 2.0 V$	-	-	0.3	-	0.3	-	0.3	V
	input voltage	$V_{CC} = 3.0 V$	-	-	0.6	-	0.6	-	0.6	V
		V <sub>CC</sub> = 5.5 V	-	-	1.1	-	1.1	-	1.1	V

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Symbol	Parameter	Conditions		25 °C		_40 °C	to +85 °C	-40 °C t	to +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
V <sub>OH</sub>	HIGH-level	$V_{I} = V_{IH} \text{ or } V_{IL}$								
	output voltage	$I_O = -50 \ \mu\text{A}; \ V_{CC} = 2.0 \ \text{V}$	1.9	2.0	-	1.9	-	1.9	-	V
		$I_{O}$ = –50 $\mu\text{A};$ $V_{CC}$ = 3.0 V	2.9	3.0	-	2.9	-	2.9	-	V
		$I_{O}$ = –50 $\mu\text{A};$ $V_{CC}$ = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		$I_{O}$ = –4.0 mA; $V_{CC}$ = 3.0 V	2.58	-	-	2.48	-	2.40	-	V
		$I_{\rm O}$ = –8.0 mA; $V_{\rm CC}$ = 4.5 V	3.94	-	-	3.8	-	3.70	-	V
V <sub>OL</sub>	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}$								
	output voltage	$I_{O}$ = 50 $\mu A; V_{CC}$ = 2.0 V	-	0	0.1	-	0.1	-	0.1	V
		$I_{O}$ = 50 $\mu\text{A};~V_{CC}$ = 3.0 V	-	0	0.1	-	0.1	-	0.1	V
		$I_O$ = 50 $\mu\text{A};~V_{CC}$ = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		$I_{O}$ = 4.0 mA; $V_{CC}$ = 3.0 V	-	-	0.36	-	0.44	-	0.55	V
		$I_{O}$ = 8.0 mA; $V_{CC}$ = 4.5 V	-	-	0.36	-	0.44	-	0.55	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = 5.5 V or GND; V <sub>CC</sub> = 0 V to 5.5 V	-	-	0.1	-	1.0	-	2.0	μA
I <sub>CC</sub>	supply current		-	-	1.0	-	10	-	40	μΑ
CI	input capacitance		-	1.5	10	-	10	-	10	pF

#### Table 7. Static characteristics ...continued

Voltages are referenced to GND (ground = 0 V).

# **11. Dynamic characteristics**

#### Table 8. Dynamic characteristics

GND = 0 V;  $t_r = t_f = \le 3.0$  ns. For test circuit see <u>Figure 6</u>.

Symbol	Parameter	ameter Conditions			25 °C		–40 °C to +85 °C		–40 °C to +125 °C		Unit
				Min	Тур	Max	Min	Max	Min	Max	
t <sub>pd</sub>	propagation	A to Y; see Figure 5	[1]								
delay	delay	$V_{CC}$ = 3.0 V to 3.6 V	[2]								
		C <sub>L</sub> = 15 pF		-	3.4	7.1	1.0	8.5	1.0	10.0	ns
		C <sub>L</sub> = 50 pF		-	4.9	10.6	1.0	12.0	1.0	13.5	ns
		$V_{CC}$ = 4.5 V to 5.5 V	[3]								
		C <sub>L</sub> = 15 pF		-	2.6	5.5	1.0	6.0	1.0	7.0	ns
		C <sub>L</sub> = 50 pF		-	3.6	7.0	1.0	8.0	1.0	9.0	ns
C <sub>PD</sub>	power dissipation capacitance	per buffer; V <sub>I</sub> = GND to $V_{CC}$	<u>[4]</u>	-	14	-	-	-	-	-	pF

[1]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .

[2] Typical values are measured at  $V_{CC}$  = 3.3 V.

[3] Typical values are measured at  $V_{CC}$  = 5.0 V.

 $\begin{array}{ll} \mbox{[4]} & C_{PD} \mbox{ is used to determine the dynamic power dissipation $P_D$ ($\mu$W). } \\ & P_D = C_{PD} \times V_{CC}{}^2 \times f_i + \sum \left( C_L \times V_{CC}{}^2 \times f_o \right) \mbox{ where:} \\ & f_i = \mbox{ input frequency in MHz;} \end{array}$ 

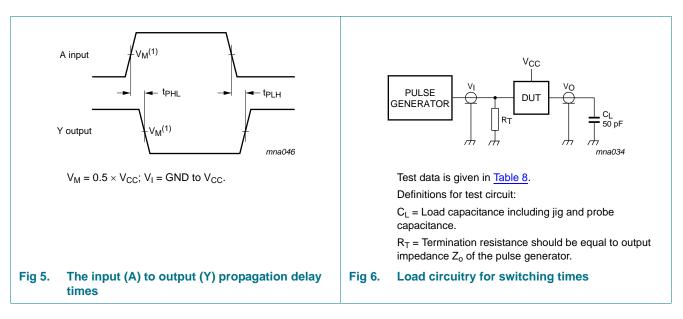
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f<sub>o</sub> = output frequency in MHz;

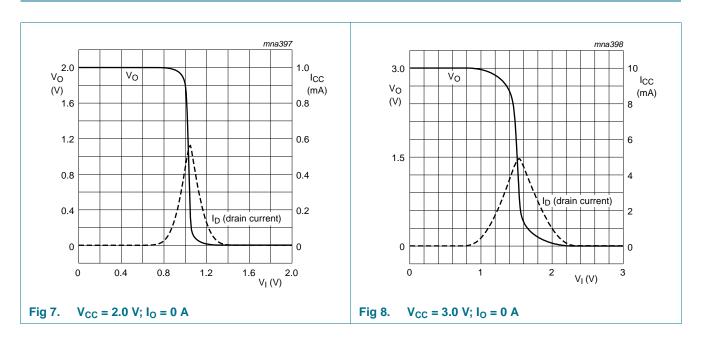
 $C_L$  = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in Volts.

## 12. Waveforms

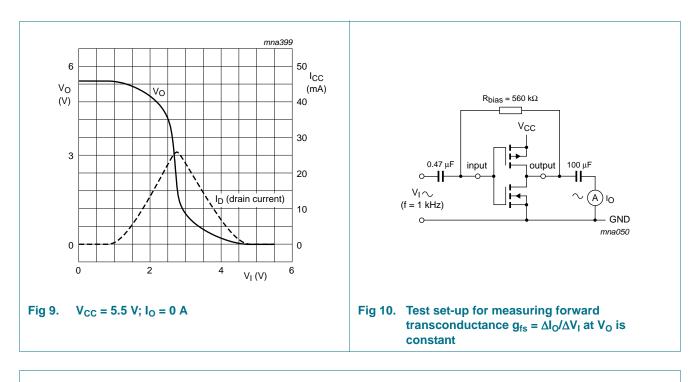


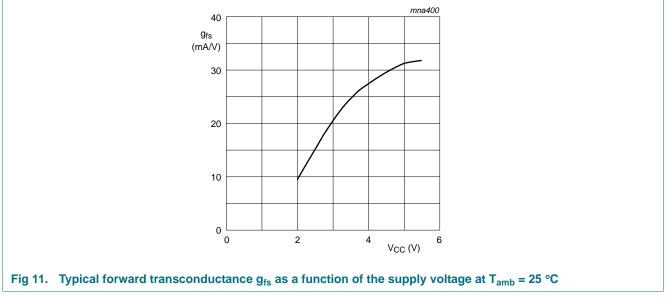
# 13. Typical transfer characteristics



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# 14. Application information

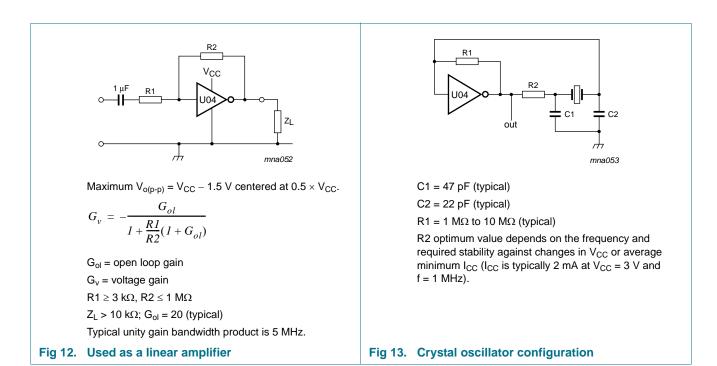
Some applications are:

- Linear amplifier (see Figure 12)
- In crystal oscillator design (see Figure 13)

Remark: All values given are typical unless otherwise specified.

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# Table 9. External components for resonator (f < 1 MHz)</th> All values given are typical and must be used as an initial set-up

All values given are typical and must be used as an initial set-up.					
Frequency	R1	R2	C1	C2	
10 kHz to 15.9 kHz	<b>22 Μ</b> Ω	220 kΩ	56 pF	20 pF	
16 kHz to 24.9 kHz	<b>22 Μ</b> Ω	220 kΩ	56 pF	10 pF	
25 kHz to 54.9 kHz	22 MΩ	100 kΩ	56 pF	10 pF	
55 kHz to 129.9 kHz	22 MΩ	100 kΩ	47 pF	5 pF	
130 kHz to 199.9 kHz	<b>22 Μ</b> Ω	47 kΩ	47 pF	5 pF	
200 kHz to 349.9 kHz	22 MΩ	47 kΩ	47 pF	5 pF	
350 kHz to 600 kHz	<b>22 Μ</b> Ω	<b>47</b> kΩ	47 pF	5 pF	

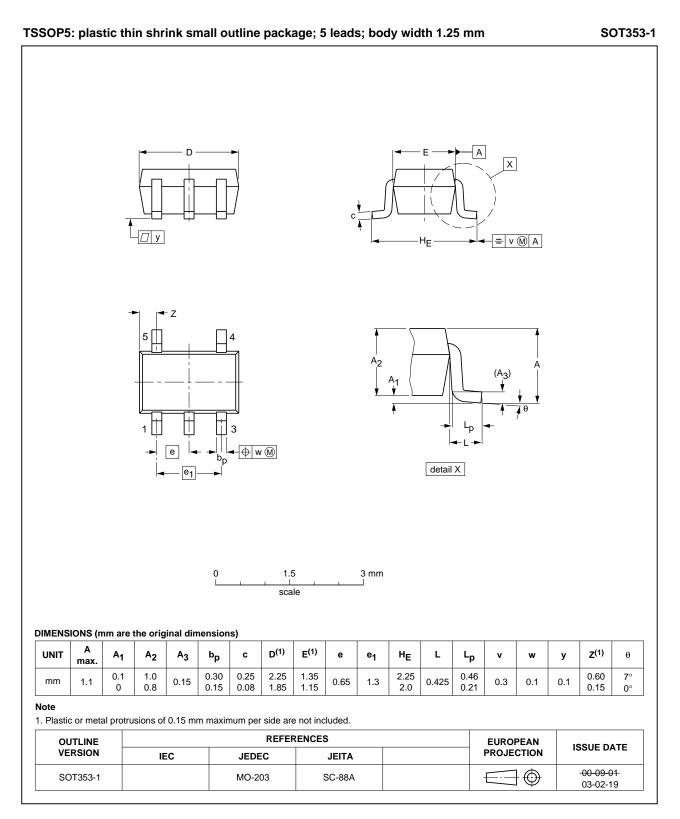
#### Table 10. Optimum value for R2

Frequency	R2	Optimum for
3 kHz	2.0 kΩ	minimum required I <sub>CC</sub>
	8.0 kΩ	minimum influence due to change in $V_{CC}$
6 kHz	1.0 kΩ	minimum required I <sub>CC</sub>
	4.7 kΩ	minimum influence by V <sub>CC</sub>
10 kHz	0.5 kΩ	minimum required I <sub>CC</sub>
	2.0 kΩ	minimum influence by V <sub>CC</sub>
14 kHz	0.5 kΩ	minimum required I <sub>CC</sub>
	1.0 kΩ	minimum influence by V <sub>CC</sub>
>14 kHz	-	replace R2 by C3 with a typical value of 35 pF

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## 15. Package outline



#### Fig 14. Package outline SOT353-1 (TSSOP5)

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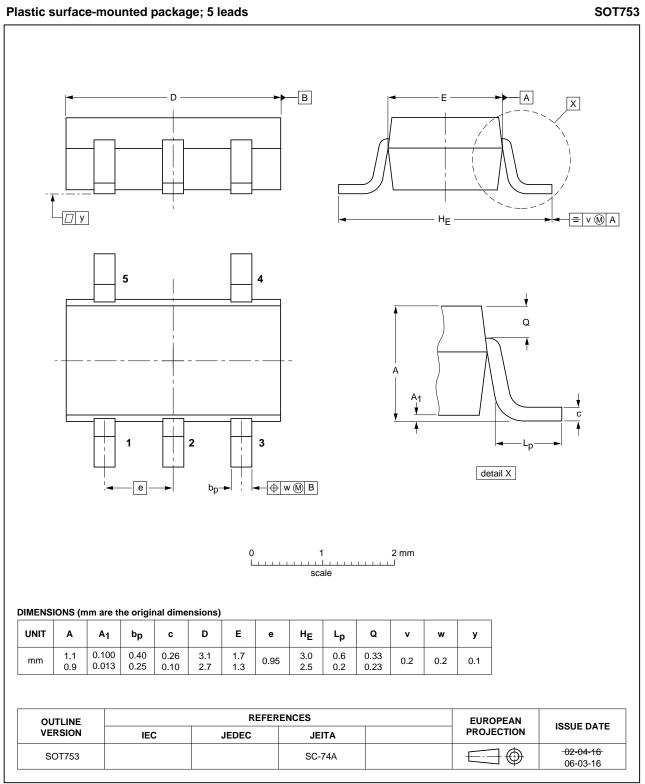


Fig 15. Package outline SOT753 (SC-74A)

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# **16. Abbreviations**

Table 11.	Abbreviations
Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MIL	Military
MM	Machine Model

# **17. Revision history**

Table 12. Revision histo	Revision history				
Document ID	Release date	Data sheet status	Change notice	Supersedes	
74AHC1GU04_Q100 v.1	20121121	Product data sheet	-	-	

## **18. Legal information**

#### 18.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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